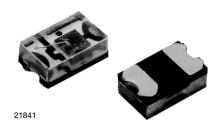


Vishay Semiconductors

Silicon PIN Photodiode



DESCRIPTION

TEMD7000X01 is a high speed and high sensitive PIN photodiode. It is a miniature surface mount device (SMD) including the chip with a 0.23 mm² sensitive area detecting visible and near infrared radiation.

FEATURES

· Package type: surface mount

• Package form: 0805

• Dimensions (L x W x H in mm): 2 x 1.25 x 0.85

Radiant sensitive area (in mm²): 0.23

· AEC-Q101 qualified

· High photo sensitivity

· High radiant sensitivity

· Suitable for visible and near infrared radiation

· Fast response times

• Angle of half sensitivity: $\varphi = \pm 60^{\circ}$

• Floor life: 168 h, MSL 3, acc. J-STD-020

• Lead (Pb)-free reflow soldering

• Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

• Find out more about Vishay's Automotive Grade Product requirements at: www.vishay.com/applications

APPLICATIONS

· High speed photo detector

| PRODUCT SUMMARY | | | | | |
|-----------------|----------------------|----------------|-----------------------|--|--|
| COMPONENT | I _{ra} (μΑ) | φ (deg) | λ _{0.1} (nm) | | |
| TEMD7000X01 | 3 | ± 60 | 350 to 1120 | | |

Note

Test conditions see table "Basic Characteristics"

| ORDERING INFORMATION | | | | | |
|----------------------|---------------|------------------------------|--------------|--|--|
| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM | | |
| TEMD7000X01 | Tape and reel | MOQ: 3000 pcs, 3000 pcs/reel | 0805 | | |

Note

MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS | | | | |
|-------------------------------------|-----------------------------------|-------------------|---------------|------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| Reverse voltage | | V _R | 60 | V |
| Power dissipation | T _{amb} ≤ 25 °C | P_V | 215 | mW |
| Junction temperature | | Tj | 100 | °C |
| Operating temperature range | | T _{amb} | - 40 to + 100 | °C |
| Storage temperature range | | T _{stg} | - 40 to + 100 | °C |
| Soldering temperature | Acc. reflow solder profile fig. 8 | T_{sd} | 260 | °C |
| Thermal resistance junction/ambient | Acc. J-STD-051 | R _{thJA} | 270 | K/W |

T_{amb} = 25 °C, unless otherwise specified







COMPLIANT



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Silicon PIN Photodiode



| BASIC CHARACTERISTICS | | | | | | |
|---|--|-------------------|------|-------------|------|------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | I _F = 50 mA | V _F | | 1 | | V |
| Breakdown voltage | I _R = 100 μA, E = 0 | V _(BR) | 32 | | | V |
| Reverse dark current | V _R = 10 V, E = 0 | I _{ro} | | 1 | 10 | nA |
| Diada canacitanas | V _R = 0 V, f = 1 MHz, E = 0 | C _D | | 4 | | pF |
| Diode capacitance | $V_R = 5 \text{ V}, f = 1 \text{ MHz}, E = 0$ | C _D | | 1.3 | | pF |
| Open circuit voltage | $E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$ | Vo | | 350 | | mV |
| Temperature coefficient of V _o | $E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$ | TK _{Vo} | | - 2.6 | | mV/K |
| Short circuit current | $E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$ | I _k | | 50 | | μΑ |
| Temperature coefficient of I _k | $E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$ | TK _{Ik} | | 0.1 | | %/K |
| Reverse light current | $E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $V_R = 5 \text{ V}$ | I _{ra} | | 3 | | μΑ |
| Angle of half sensitivity | | φ | | ± 60 | | deg |
| Wavelength of peak sensitivity | | λ_{p} | | 900 | | nm |
| Range of spectral bandwidth | | λ _{0.1} | | 350 to 1120 | | nm |
| Rise time | $V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega,$ $\lambda = 820 \text{ nm}$ | t _r | | 100 | | ns |
| Fall time | $V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega,$ $\lambda = 820 \text{ nm}$ | t _f | | 100 | | ns |

Note

 T_{amb} = 25 °C, unless otherwise specified

BASIC CHARACTERISTICS

 T_{amb} = 25 °C, unless otherwise specified

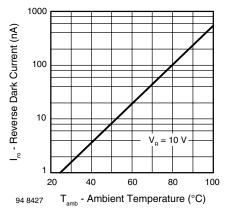


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

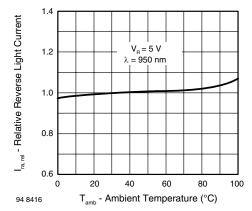


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature



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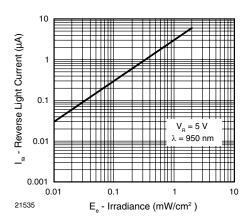


Fig. 3 - Reverse Light Current vs. Irradiance

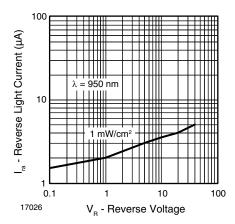


Fig. 4 - Reverse Light Current vs. Reverse Voltage

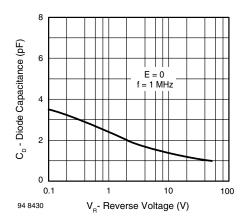


Fig. 5 - Diode Capacitance vs. Reverse Voltage

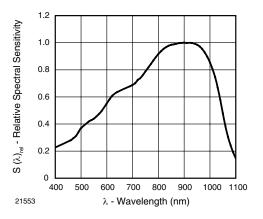


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

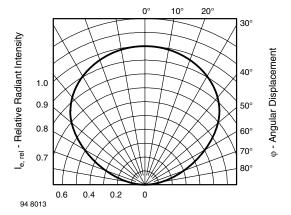


Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

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REFLOW SOLDER PROFILE

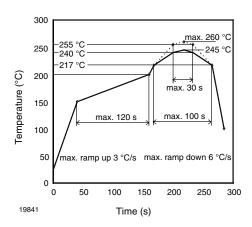


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

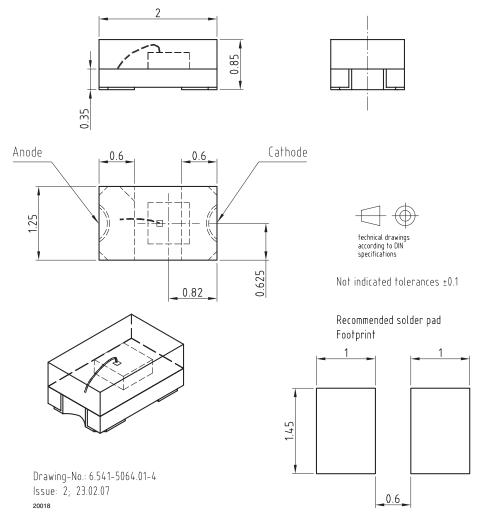
Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 3, acc. to J-STD-020.

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 $^{\circ}$ C.

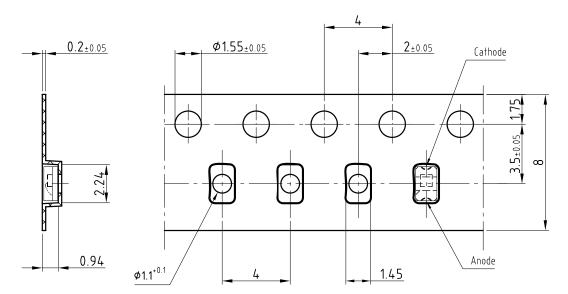
PACKAGE DIMENSIONS in millimeters



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BLISTER TAPE DIMENSIONS in millimeters



Reel off direction

technical drawings according to DIN specifications

Drawing-No.: 9.700-5311.01-4

Issue: 1; 23.02.07

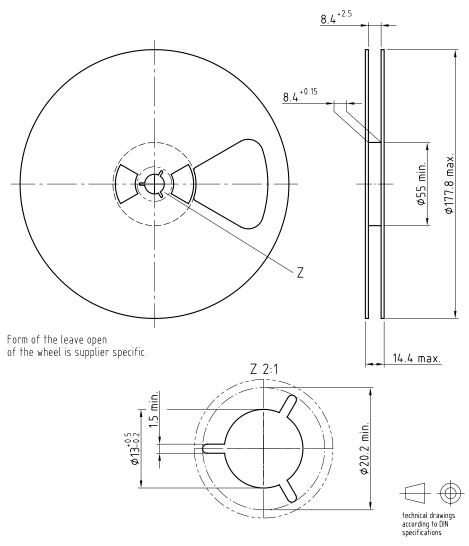
21501

Not indicated tolerances ±0.1

Silicon PIN Photodiode



REEL DIMENSIONS in millimeters



Drawing-No.: 9.800-5096.01-4

Issue: 1; 05.05.08

20875



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